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April 1st, 2010 Renesas Electronics Corporation

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The semiconductor operations of Hitachi and Mitsubishi Electric were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Mitsubishi Electric, Mitsubishi Electric Corporation, Mitsubishi Semiconductors, and other Mitsubishi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Note: Mitsubishi Electric will continue the business operations of high frequency & optical devices and power devices.

Renesas Technology Corp. Customer Support Dept. April 1, 2003



M51403FP/GP

PAL VIDEO CHROMA SIGNAL PROCESSOR

DESCRIPTION

The M51403FP/GP is a semiconductor integrated circuit for processing video signals in a PAL system color liquid crystal (LC) television set.

This IC incorporates ACC, APC, VCXO, RGB matrix amplifier, color signal demodulator, picture quality control, killer circuit and ID circuit.

FEATURES

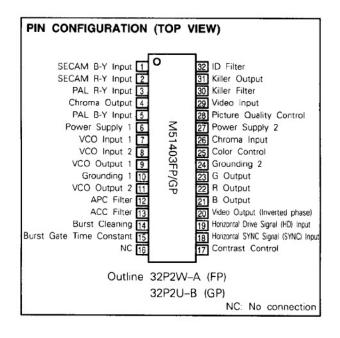
- · Low power dissipation
- PAL/SECAM dual system can be configured by combination with M51404AFP (SECAM chroma IC)
- 32-pin flat package

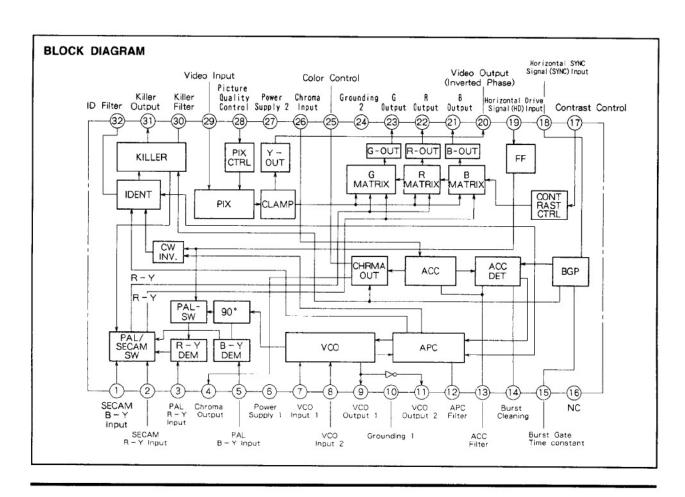
APPLICATION

LCD, TV

RECOMMENDED OPERATING CONDITION

Supply voltag	e range	.4.0 ~ 5.0V
Rated supply	voltage	4.5V







PAL VIDEO CHROMA SIGNAL PROCESSOR

ABSOLUTE MAXIMUM RATINGS

Symbol	Parametr	Ratings	Unit			
Vcc	Supply voltage	5.0	V			
Surge	Surge withstand voltage (200pF)	± 300*	V			
VIN®	Input amplitude at pin ®	500	mVP-P			
lout@	Outflow current at pin 3	800	mA			
lou⊤⊗	Outflow current at pin @	900	mA			
VIN @	Input voltage at pin ®	Vcc + 0.3				
VIN®	Input voltage at pin (9)	Vcc + 0.3				
lout ∰ ∰	Outflow current at (1), (2), (3)	900	mA			
lout 1 Outflow current at pin 1		450	mA			
Pσ	Internal power dissipation	600 (FP) 430 (GP)	mW			
Topr	Operating temperature	- 20~75	℃			
Tstg	Storage temperature	- 40~125	℃			

^{*:} The voltage on pins ①, ②, ⑤ is ± 200 V.

ELECTRICAL CHARACTERISTICS (Ta = 25 °C, unless otherwise noted)

Symbol	Parameter	Test	Test method		Unit			
Symbol	r al attletel		The numbers in circle below indicate Pin Nos.	Min.	Тур.	Max.	Unit	
lcc	circuit current	1	Weasure the inflow current when 4.5 VDC of voltage is applied to pin (6), 60.	15	20	27	mA	
Video Sec	etion		, p., g., p.		-	-		
Ymax	Maximum output	2	Input 100kHz sine wave of 0.3 Vp-p to pin 🚳, and measure the output amplitude at pin 🔁 when the voltage at pin 🗇 is 4.5 Vpc.	1.8	2.2	2.7	VP-P	
GY	Video amplifier gain	3	Input 100kHz sine wave of 0.3 Vp - p to pin 😭 and measure the output amplitude at pin 🐧 when the voltage at pin 🐧 is 1.0 V DC to calculate the ratio between the measured amplitude and input amplitude.	11	14.3	16	dB	
YCTRST (2.0)			Input 100kHz sine wave of 0.3 Vp - p to pin (3), and when the voltage at pin (1) is changed to 2.0, 0.5 and	0.5	3.0	5.0	dB	
YCTRST (2.5)	Contrast control characteristics		0 Vpc, measure each outout amplitude at pin 20	- 8.0	- 4.8	- 3.0	dB	
YCTRST (0)			to calculate the measured amplitude to Test 3 output amplitude ratio.	- 50	- 19	- 14	dB	
Y TONE (4.5)	Picture quality control	5	Input 1.5 MHz sine wave of 0.3 Vp-p to pin 🚱, and when the voltage at pin 🕅 is 1.0 Vpc, and the voltage at pin 🔞 is changed to 2.25, 4.5 and 0 Vpc.	- 4.0	- 2.6	- 1.5	dB	
YTONE(0)	characteristics	5	voltage at pin (a) is charged to 2.25, 4.5 and 0 VDC, measure each output amplitude at pin (a) to calculate the ratio of the measured amplitude to the output amplitude when the voltage at pin (a) is 2.25VDC.		5.7	7.0	dB	
YFREQ	Frequency characteristics		Input 200kHz and 2 MHz sine waves of 0.3 Vp-p to pin (2), and when the voltage at pin (2) and (1) are 2.25 and 1.0 Vpc respectively, measure the output amplitude at pin (2) to calculate the ratio between the measured amplitude and output amplitude at 2 MHz in relation to 200 kHz.	- 9.5	- 6.2	- 3.5	dB	
Chroma S	Section							
Cmax	Maximum output	7	Input a sine wave of 0 dB to pin 🗞 and measure the output amplitude at pin 🐒 when the voltage at pin 🛈 😝 are 4.5 Vpc.	1.5	2.0	2.5	VP-P	
Gc	Chroma maximum gain	8	Input a sine wave of -26 dB to pin ∰s, and when the voltage at pins ∰ are 4.5 v 0C, measure the output amplitude at pin ∰s to calculate the ratio between the measured amplitude and input amplitude.	45	52	57	dB	
CACC(+6)			Input sine wave of 0, +6, -20 dB to pin 6, and when the voltage at pin 7, 6 are 1.0 and 0.3 Vpc	0	0.1	2.0	dB	
	ACC control characteristics	9	respectively, measure each putput amplitude at pin 20 to					
CACC(-20)			calculate the ratio between the measured amplitude and output amplitude at 0 dB input.	- 6.0	- 1.8	0	dB	
CIKLR	Killer operation input	10	Input PAL simple chroma signal of 0 d8 to pin \$\ \&\\ \end{aligned}, reduce the amplitude, measure the input amplitude when the voltage at pin \$\ \end{aligned}\ exceeds 2.9 V, and calculate the ratio of the measured amplitude to the input amplitude at 0 d8.		- 48	- 40	dB	
DKLR	Killer color residual	11	Input a sine wave of 0 dB to pin & and measure the output amplitude at pin ① when the voltage at pin ①. ⑤ are 1.0 and 0.3 Voc respectively.	0	10	30	mVP –	
CSAT (4.5)			Input a sine wave of 0 dB to pin 6, and when the voltage at pin (0, is 1.0 Vpc, and the voltage at	1.5	3.5	6.0	dB	
CSAT (1.0)	Color saturation control	10	pin (3) is changed to 4.5, 1.0, 0.5, 0.3 and 0.1 Vpc.	1.5	3.5	6.0	dB	
CSAT (0.5)	characteristics	12	measure each output amplitude at pin (1) to calculate the ratio between the measured amplitude and the	1.0	3.0	5.5	dB	
CSAT (0.1)	characteristic fields (2000)		output amplitude when the voltage at pin \$ is 0. 3Vpc (To be continued)	- 16	- 13	- 10	dB	

M51403FP/GP

PAL VIDEO CHROMA SIGNAL PROCESSOR

ELECTRICAL CHARACTERISTICS (cont.)

Symbol	Parameter	Test No.	Test method		Unit		
5,,,,,			The numbers in circle below indicate Pin Nos.	Min.	Тур.	Max.	Offic
CCTRL (4. 5)			Input a sine wave of 0 dB to pin 🚳, and when the voltage at pin ①, 🍪 are 4.5 Voc, measure the amplitude at pin ④:it shall be CCTRL(4.5).	0.8	1.2	1.6	VP-P
CCTRL (2. 0)	Color control characteristics	13	In the same manner, measure the output amplitude at pin@ when the voltage at pin a is 2.0 and 0.5 Vpc to	- 6	- 2.8	0	dB
CCTRL (0. 5)			calculate the ratio between the mwasured amplitude and CCTRL(4.5): te amplitude shall be CCTRL(2.0) and CCTRL (0.5) respectively.	- 20	- 17	- 14	dB
Δ fvco	VCO free run frequency	14	Input only SYNC to pin (6) and measure the oscillation frequency at pin (1) to calculate the difference from 4.433619 MHz. (No input at pin (8))	- 950	0	+ 950	Hz
Δ fvcopuli	APC pull - in range	15	Input a sine wave of 0 dB to pin 39 and change tha frequency. Measure the input frequency at which the voltage at pin 30 change from "H" to "L." (The center frequency shall be 4,4336;9MMZ.)	+ 200	+ 300 - 300	- 200	Hz
Dв	B demodulator sensitivity	16	Input a sine wave of 0 dB to pin 30 and measure the output amplitude at pin 100 when the voltages at pin 100, 25 are 1.0 and 0.3 Voc respectively.	0.4	0.7	1.2	VP-P
R (R/B)	Demodulated output voltage	17	Input a sine wave of 0 dB to pin 🚳 and measure the output amplitude at pin 😩, 🥸 when the voltages at pin 🛡, 😂	0.40	0.57	0.70	-11
R (G/B)	ratio	17	are 1.0 and 0.3 Vpc respectively to calculate the ratio between the measured amplitude and the output amplitude in Test No. 16 above.	0.25	0.35	0.45	-
DleakB		2020	Input a sine wave of 0 dB to pin 🚳 and measure the output amplitude at pin ② , ② , ② for the element of 8.9 MHz when the voltages at pins ⑩, ⑤ are 1.0 and 0 Vpc	0	8	25	mVP - F
DieakR	Demodulated output carrier leak	18		0	8		mVP - F
DleakG		-	respectively.	0	8	25	mVP - F
RDC	BAL /SECAM DC		Measure each DC voltage difference at pin ②, ②, ② when pin ③ is grounded with Vcc AT 10KΩ with noinput at pins ③ and ③.	0	19	50	mVDC
GDC	PAL/SECAM output DC voltage difference	19		0	6	50	mVDC
Вос			* 4.5 Voc for voltage at pin 10 and 18	0	10	50	mVDC
V31KLR-H	"H" voltage at killer pin	20	Input only SYNC and measure each DC voltage at pin when pin sis connected through 10kΩ to "GND"	3.3	3.7	4.5	VDC
V31KLR-L	"L" voltage at killer pin	20	(L)," and it is connected to "V _{cc} (H)" in the same manner.(No input at pin 6)	0	0.1	0.3	V _{DC}
VCONT	Voltage at no signal input	21	Measure output DC voltage at pin 29 when no signal is input.	2.7	3.1	3.7	V
Gco	Luminance amplifier gain	22	Input 100 kHz sine wave of 0.1 Vp-p to pin 🚳 and measure the output amplitude at pin 🚳 to calculate the ratio between the measured amplitude and input amplitude.	11.0	14.0	17.0	dB
Gmax	Maximum output	23	input 100 kHz sine wave of 0.5 Vp-p to pin 🚳 and measure the output amplitude at pin 🔞 .	1.7	2.5	3.0	VP-P
SB	SECAM demodulated luminance	24	Input 100 kHz sine wave of 0.3 Vp-p to pin ① .② when pin �� is connected through 10 K Ω to "Vcc" with pin ⑦ =1,0 Vpc and pin�� =0 Vpc, and measure the output amplitude at pin ��.	0.7	1.0	1.3	VP-P
SR (R/B)	SECAM demodulated output	25	Measure the output amplitude at pin 20, 39 under the conditions in Test No. 24 above, and calculate the ratio	0.55	0.67	0.80	
SR (G/B)	voltage ratio		between the measured amplitude and output amplitude in Test.	0.45	0.55	0.65	-



SWITCH CONDITIONS IN TEST CIRCUIT

Test		Pin Voltage (VDC)							S					W		
No.	1	8	8	289	23	30	Sı	Sз	S17	S19	S25	S26	S28	S29-1	S29-2	S30
1	2.7	2.25	4.5	2.25			OFF	OFF	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF
2	4.5	0	4.5	2.25			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
3	1.0	0	4.5	2.25			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
4	2.0 0.5 0	0	4.5	2.25			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
5	1.0	. 0	4.5	2.25 4.5 0			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
6	1.0	0	4.5	2.25			OFF	ON	OFF	ON	ŎΝ	ON	ÖFF	ON	OFF	OFF
7	4.5	4.5	4.5	2.25	2.9	0	OFF	OFF	ON							
8	4.5	4.5	4.5	2.25	2.9	0	OFF	OFF	ON							
9	1.0	0.3	4.5	2.25	2.9	0	OFF	OFF	ON							
10	1.0	0.3	4.5	2.25	2.9		OFF	OFF	OFF							
11	1.0	0.3	4.5	2.25	2.9	4.5	OFF	OFF	ON							
13	4.5	4.5 2.0 0	4.5	2.25	2.9	0	OFF	OFF	ON							
14	1.0	0.3	4.5	2.25	2.9		OFF	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF
15	1.0	0.3	4.5	2.25	2.9	14(0)(0)(0)(0)	OFF	OFF	OFF							
16	1.0	0.3	4.5	2.25	2.9	0	OFF	OFF	ON							
17	1.0	0.3	4.5	2.25	2.9	0	OFF	OFF	ON							
18	1.0	0	4.5	2.25	2.9	0	OFF	OFF	ON							
19	4.5	4.5	4.5	4.5		4.5 0	OFF	OFF	ON							
20	1.0		4.5	2.25	2.9	4.5	OFF	OFF	OFF	OFF	OFF		OFF	OFF	OFF	ON
21	1.0	0	4.5	2.25	100		OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
22	1.0	0	4.5	2.25			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
23	1.0	0	4.5	2.25			OFF	ON	OFF	ON	ON	ON	OFF	ON	OFF	OFF
24	1.0	0.3	4.5	2.25	2.9	4.5	ON	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
25	1.0	0.3	4.5	2.25	2.9	4.5	ON	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	QN

* Normally S5 should be OFF.

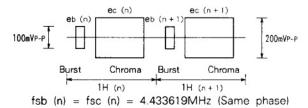
Input Pulse Pin Threshold

HD pulse	Pin ⑲	
Sync PULSE	Pin ®	

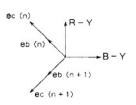
- NOTE: When a pulse is input with the HD pulse polarity facing downward " " :
- Fall position: This position should be within the fly-back period and shead of the burst signal.
- Rise position:This position should be within the fly-back period and not come into contact with the image.

ELECTRICAL CHARACTERISTICS TEST METHOD NOTE1. "Sine wave of 0dB" in the chroma section above refers to 4.43MHz, 100mV_{P-P}.

NOTE2. PAL simple chroma signal (0dB)



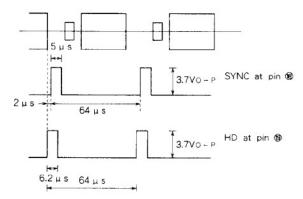
The phase relation of the above signal is as shown on the right. The phase relation of ec (n) and ec (n+1) to the burst may not always be as shown in the figure above: the test items for the phase relation in particular should be variable.



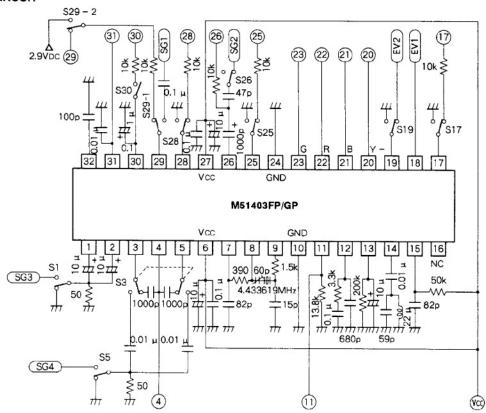
The above timing is standard: there is an allowance of 1.5 μs after SYNC fall and 12 μs before SYNC fall in HD rise, and 2 to 7.5 μs in HD width.

The input amplitude should be 1.7Vo-P~Vcc.

INPUT SIGNAL



TEST CIRCUIT

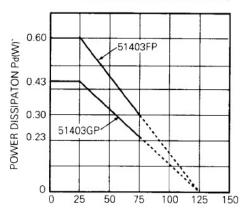


Units Resistance: Ω

Capacitance: F

TYPICAL CHARACTERISTICS

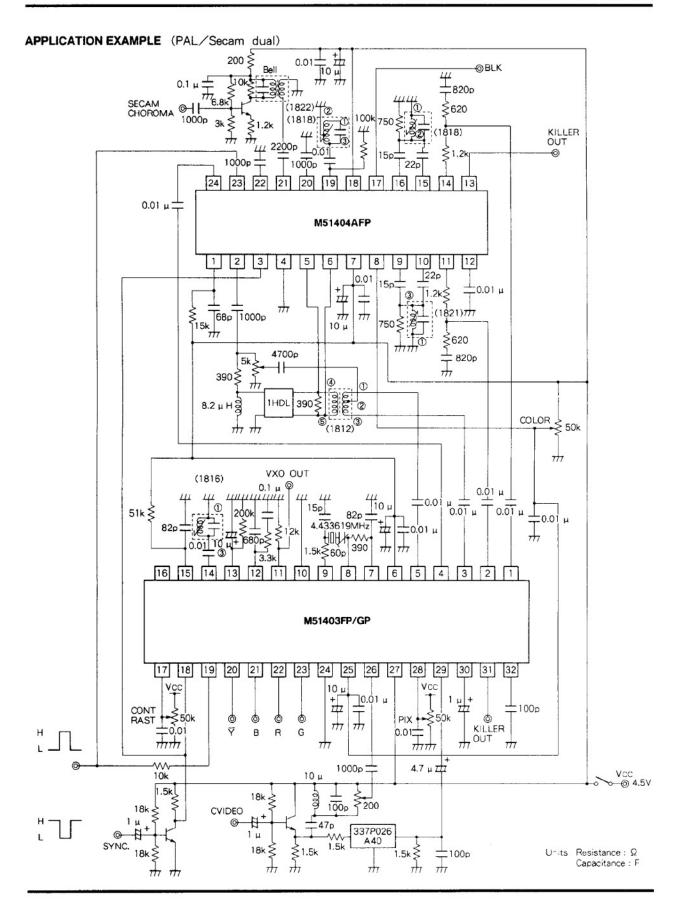
THERMAL DERATING (MAXIMUM RATING)



AMBIENT TEMPERATURE Ta(°C)

M51403FP/GP

PAL VIDEO CHROMA SIGNAL PROCESSOR



DESCRIPTION OF PIN

	N OF PIN	
Pin No.	Name	Peripheral circuit of pins
1	SECAM	3 (5)
	B-Y Input	PPTT
2	SECAM	10k
	R-Y Input	
3	PAL	10k
	R-Y Input	- 10k
(5)	PAL	
	B-Y Input	GND
4	Chroma Output	Vcc 4
6	Vcc1	
⑦	VCO Input 1	VCC GND
8	VCO Input 2	1k2 10.5k 8 GND
9	VCO Output 1	34 © 200 38 © 200 300

PAL VIDEO CHROMA SIGNAL PROCESSOR

Pin No.	Name	Peripheral circuit of pins
10	GND	
111	VCO Output 2	Vcc **
12	APC Filter	12.5k
(3)	ACC Filter	GND GND
14	Burst Cleaning	Vcc 3.8k

Pin No.	Name	Peripheral circuit of pins
(6)	Burst Gate Time Constant	Vcc (15)
16	N.C.	
Œ	Contrast Control	Vcc W W GND
18	Horizontal Sync Signal Input (SYNC)	VCC (B) (B) (GND
19	Horizontal Drive Signal Input (HD)	Vcc IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII

Pin No.	Name	Peripheral circuit of pins
Ø	VIDEO Output (Inverted phase)	Vcc ŠŠ ŽŠ GND
2)	B Output	—— ∨cc ŏ\$
22	R Output	1 (2) (2) (2) (2)
23	G Output	GND GND
29	GND	
<u>2</u>	Color Control	W S S S S S S S S S S S S S S S S S S S
Ø	Chroma Input	26 10k
Ø	Vcc2	
239	Picture Quality Control	W 20K YOE GND

PAL VIDEO CHROMA SIGNAL PROCESSOR

Pin No.	Name	Peripheral circuit of pins
3	VIDEO Input	29 Vcc
30	Killer Filter	Vcc Vcc GND
3	Killer Output	31 GND
2	ID Filter	GND 33 Acc